

朝貴電子股份有限公司 CKM ELECTRONICS CO., LTD.

## PRODUCT SPECIFICATION

CKM 2514 Series

# 2.50 mm PITCH CONNECTOR

### **REVISION HISTORY:**

REV	<b>REVISION DESCRIPTION</b>	DATE	CREATED/REVISED
А	NEW RELEASE	2006.04.03	
В	UPGRADE THE FORM	2013.10.20	Qinggang yang
С	UPGRADE THE FORM	2014.09.09	Guobao Lee
D	UPGRADE THE FORM	2015.11.24	Zisen Wei

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### 1.0. SCOPE

1.1 This specification covers performance, tests and quality requirements for the CKM Connectivity 2.5 Connector System. The CKM 2.5 product is a wire-to-board connection consisting of crimp-snap contacts seated in a housing that mates to 0.6 mm diameter post headers on 2.5 mm centerline and is designed to be terminated to 20 to 28 AWG wire.

### 1.2: Qualification

When tests are performed on the subject product line, procedures specified in Figure 1 shall be used. All inspections shall be performed using the applicable inspection plan and product drawing.

### 2.0. APPLICABLE DOCUMENTS

At the time of this specifications release, the latest revisions of the following

Documents were used. These documents shall form a part of this specification as describe with in this document.

Industry Specifications / Standards

UL-94 Flammability

ASTM B-103 Phosphor Bronze or Brass Plate, Rod, Sheet, Strip and Rolled Bar

**EIA Specifications** 

EIA-364-D Electrical Connector/Socket Test Procedures Including Environmental Classifications

### 3.0. REQUIREMENTS

- 3.1 Design and Construction
  - Product shall be of the design, construction and physical dimensions specified on the applicable product drawing
- 3.2 MATERIAL

Materials used in the construction of this product shall be as specified on the applicable product drawing 3.3 Ratings

1. Voltage: 250 volts AC.

2. Current: See Figure 4 for applicable current carrying capability. Maximum rated current that can be carried by this product is limited by maximum operating temperature of the housings (85°C) and temperature rise of the housings (30°C). Variables to be considered for each application are: wire size, connector size, contact material, ambient temperature, and printed circuit board design.

- 3. Temperature: -25℃~ 85℃
- 4. Rated Current: 3A AC/DC
- 3.4 Performance and Test Description.

Product is designed to meet the electrical, mechanical and environmental performance requirements specified in Figure 1. Unless otherwise specified, all tests shall be performed at ambient environmental conditions.

3.5 Test Requirements and Procedures Summary

Test Description	Requirement	Procedure
Initial examination of product.	Meets requirements of product drawing and Application	EIA-364-18.Visual and dimensional (C of C) inspection per product drawing

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Final examination of product.	Meets visual	requirements.	EIA-364-18.Visual inspection.			on.
		ELECTR	ICAL			
Low Level Contact Resistance (LLCR).	initial. 20	ns maximum milli ohms um final.	EIA-364-23.Subject specimens to 100 milli amperes maximum and 20 milli volts maximu open circuit voltage. See Figure 3.			
Insulation resistance.	initial.500	ohms minimum mega ohms um final.	EIA-364-21.500 volts DC, 2 minute hold. Test between adjacent contacts.			
Withstanding voltage.	old with no flashover. eres maximum ent.	EIA-364-20, Condition I.1000 volts AC at s level. Test between adjacent contacts.				
Temperature rise vs current.	m temperature ed current.		EIA-364-70, Method 1.Stabilize at a single current level until 3 readings at 5 minute intervals are within 1°C.See Figure 4.			
		MECHAN	IICAL			
Solder-ability dip test.	shall have a older coverage.	Soldering time: 3±0.5 second Soldering pot: 245±5°C				
Random vibration. microsect		tinuities of 1 E nd or longer . See Note		EIA-364-28, Test Condition VII, Condition Letter D. Subject mated specimens to 3.10 G's rms between 20 to 500 Hz.		
Mechanical shock. microseco		ond or longer durat		EIA-364-27, Method H. Subject mated specim 30 G's half-sine shock pulses of 11milliseco duration. Three shocks in each direction applied 3mutually perpendicular planes, 18 total sho		nilliseconds n applied along
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force of the Wafer. 1.0kg minimum at a rate of 25.4 mm per minute.   ENVIRONMENTAL   Thermal shock. See Note. EIA-364-32, Test Condition I. Subject mat specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minut transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition A. 40±2°C, 90~95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Figure 1(End)					T			
Mating force. 8.9 N maximum per contact. specimens with companion headers a disfance of 1 mm from point of initial contact at a maximum rate 12.7 mm per minute.   Un mating force. 0.9 N minimum per contact. EIA-364-13.Measure force necessary to un ma specimens from companion headers at a maximum rate of 12.7mm per minute.   Crimp tensile force. 1.85kg minimum EIA-364-3.Determine crimp tensile at a rate of 2 mm per minute.   Contact retention force. 1.0kg minimum EIA-364-29.Apply axial load at a rate of 4.4 N p second and hold for 6 seconds.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-3.Determine contact retention of the wa at a rate of 2.4 mm per minute.   Thermal shock. See Note. EIA-364-3.Determine contact retenteres at 1 min transition between temperature extremes and 1 min transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition 3. Time Condition 4. Subject mated specimens to 85°C vite 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3. Time Condition 4. Subject mated specimens to 85°C of 96 hours	Durabil	lity.	See No	ote.		companion headers for 3	0 cycles a	at a maximum
Un mating force. 0.9 N minimum per contact. specimens from companion headers at a maximum rate of 12.7mm per minute   Crimp tensile force. 1.85kg minimum EIA-364-8.Determine crimp tensile at a rate of 2 mm per minute.   Contact retention force. 1.0kg minimum EIA-364-29.Apply axial load at a rate of 4.4 N p second and hold for 6 seconds.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-8.Determine contact retention of the wa at a rate of 25.4 mm per minute.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-3.Determine contact retention of the wa at a rate of 25.4 mm per minute.   Thermal shock. See Note. EIA-364-32, Test Condition 1. Subject mate specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minut transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition A. 40±2°C, 90–95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Figure 1(End) Figure 1(End) Figure 1(End)	Mating fo	orce.	8.9 N maximum	ı per contact.	spec	imens with companion hea from point of initial contac	aders a di ct at a ma:	stance of 5.08
force. 1.88kg minimum mm per minute.   Contact retention force. 1.0kg minimum EIA-364-29.Apply axial load at a rate of 4.4 N p second and hold for 6 seconds.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-8.Determine contact retention of the wa at a rate of 25.4 mm per minute.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-8.Determine contact retention of the wa at a rate of 25.4 mm per minute.   ENVIRONMENTAL   Thermal shock. See Note.   Humidity See Note. EIA-364-31, Method II. Test Time Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Figure 1(End)	Un mating fo	force.	0.9 N minimum	per contact.		cimens from companion h	neaders a	t a maximum
force. I.Okg minimum second and hold for 6 seconds.   Contact retention force of the Wafer. 1.0kg minimum EIA-364-8. Determine contact retention of the wa at a rate of 25.4 mm per minute.   ENVIRONMENTAL   Thermal shock. See Note. EIA-364-32, Test Condition I. Subject mat specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minut transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition 3, Time Condition A. 40±2°C, 90–95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°Cfor 96 hours			1.85kg mi	nimum	EIA	•		a rate of 25.4
force of the Wafer. 1.0kg minimum at a rate of 25.4 mm per minute.   ENVIRONMENTAL   Thermal shock. See Note. EIA-364-32, Test Condition I. Subject mat specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minut transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition A. 40±2°C, 90~95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Figure 1(End)								
Thermal shock. See Note. EIA-364-32, Test Condition I. Subject math specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minute transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition A. 40±2°C, 90~95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, Time Condition A. Subject mated specimens to 85°C for 96 hours   Figure 1(End) Figure 1(End)	1 0 0 0 0			nimum	EIA-364-8.Determine contact retention of the wafe at a rate of 25.4 mm per minute.			
Thermal shock. See Note. specimens to 10cycles between -55 and 85°C with minute dwells at temperature extremes and 1 minut transition between temperatures   Humidity See Note. EIA-364-31, Method II. Test Time Condition A. 40±2°C, 90~95% RH, 96 hours   Temperature life. See Note. EIA-364-17, Method A, Test Condition 3, The Time Condition A. Subject mated specimens to 85°Cfor 96 hours   Figure 1(End)				ENVIRONM	IENTA	\L		
A. 40±2°C, 90~95% RH, 96 hours   Temperature life. EIA-364-17, Method A, Test Condition 3, T   Temperature life. See Note.   Figure 1(End)	Thermal sho	See No	te.		mens to 10cycles betwee te dwells at temperature e	n -55 and extremes a	85°C with30 and 1 minute	
Temperature life. See Note. Time Condition A. Subject mated specimens to 85°Cfor 96 hours   Figure 1(End)	Humidity See No			te.				
	Temperature life. See No		See No	te.				
	   	I_		Figure 1(E	nd)			
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### NOTE

Shall meet visual requirements, show no physical damage, and meet requirements of additional tests as specified in the Product Qualification and Requalification Test Sequence shown in Figure2.

			Т	est Grou	ıp		
Test or Examination	А	В	С	D	Е	F	G
			Test	Sequenc	e (a)		
Examination of Product	1,5	1,7	1	1	1,3	1	1,5
Contact Resistance	2,6	2,8					2,4
Insulation Resitance		3,9					
Dielectric withstanding Voltage		4,10					
Terminal crimp Tensile strength			2				
Terminal/Housing Insertion Force (For Plug)				2			
Mating & Un-mating force	3						
Durability	4						
Temperature Rise						2	
Vibration					2		
Temperature life.							3
Humidity		6					
Thermal shock		5					
Sample Size	5	5	5	5	5	5	5

#### Figure 2

### NOTE:

(a)See paragraph 4.1.A.

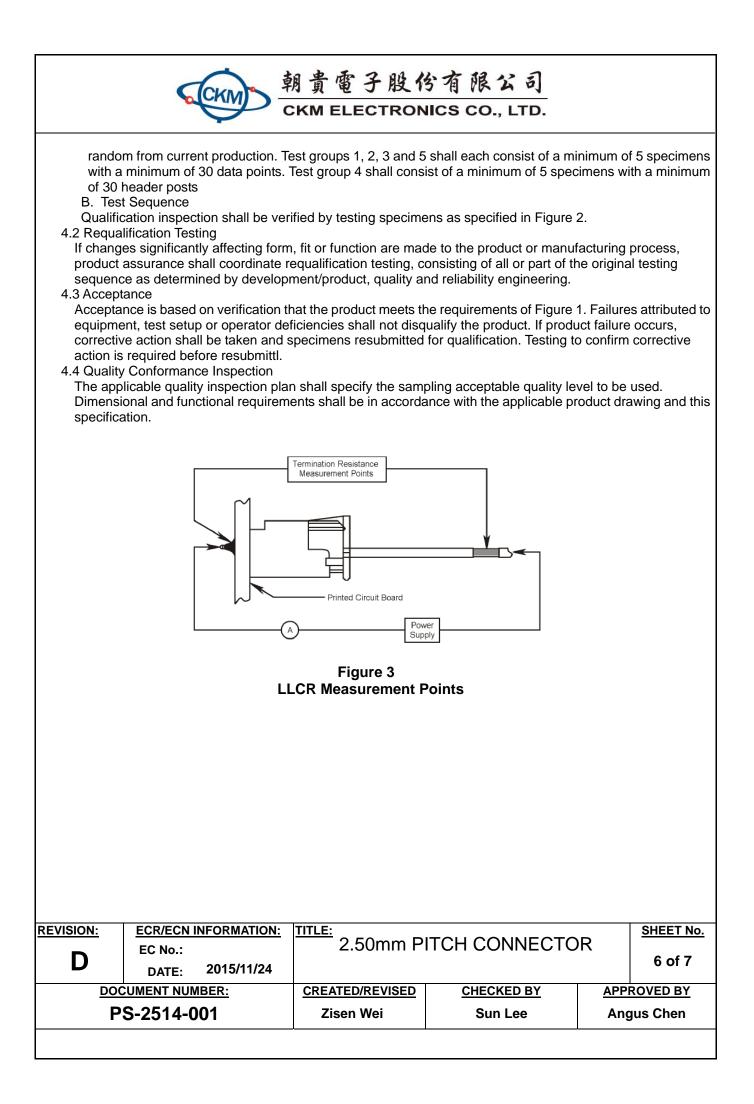
(b)Numbers indicate sequence in which tests are performed. (c)Precondition specimens with 10 durability cycles.

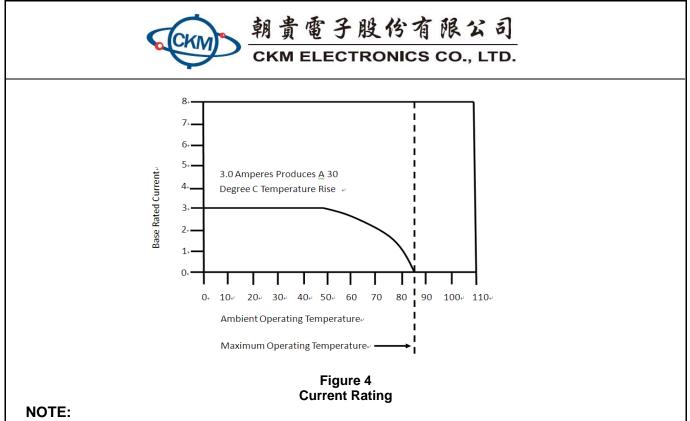
### 4. QUALITY ASSURANCE PROVISIONS

- 4.1 Qualification Testing
  - A .Specimen Selection

Specimens shall be prepared in accordance with applicable Instruction Sheets and shall be selected at

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To determine acceptable current carrying capacity for percentage connector loading and wire gage indicated, use the Multiplication Factor (F) from the above chart and multiply it times the Base rated Current for a single circuit at the maximum ambient operating temperature shown in Figure 4.

### 5. Crimping Specification:

Fix the crimped terminal, apply axial pull out force on the wire at a constant speed of 25±3mm/min (Based upon JIS C5402 6.22)

				2514T0X->	<				
Wire size(/			(AWG)	#22 #24 #26		#26	#2	8	
CONDUC			CRIMP VIDTH	1	1.50	)±0.1			
		CTOR (mm)	CRIMP HEIGH	IT 0.7~0.73	0.66~0.7	0.62~0.66	0.58~	0.62	
		SULATION (mm)		4	1.	.80			
	INSULF		CRIMP HEIGHT	T 1.79	1.76	1.76 1.73		0	
CRIM		ЛР	4.0Kgf	3.0Kgf	1.8Kgf	1.1	<gf< th=""></gf<>		
	STRENGTH			NGTH (MIN) (MIN) (MIN)		(MIN)	(MI	N)	
				Figure 5 Crimping Spec					
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